ΡΛΝ	JIT
	SEMI
	CONDUCTOR

100V N-Channel Enhancement Mode MOSFET – ESD Protected

100 V Current 300mA

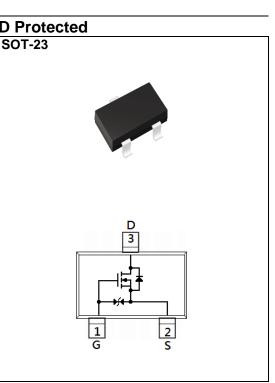
Features

Voltage

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@300mA < 6\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@200mA<9\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0003 ounces, 0.0084 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V _{DS}	100	V	
Gate-Source Voltage	V _{GS}	<u>+</u> 20		
Continuous Drain Current(Note 4)	lo	300	mA	
Pulsed Drain Current ^(Note 1)	I _{DM}	800		
Power Dissipation	Ta=25⁰C	PD	500	mW
	Derate above 25°C		4	mW/ºC
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	٥C
Typical Thermal Resistance - Junction to Ambient ^(Note 3,4)		R _{θJA}	250	°C/W



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	BV _{DSS} V _{GS} =0V, I _D =250uA 1	100	-	-	V
Gate Threshold Voltage	VGS(th)	V _{DS} =V _{GS} , I _D =250uA	250uA 1.5 1.77 2.4	2.5	V	
Drain-Source On-State Resistance	R _{DS(on)}	V_{GS} =10V, I_{D} =300mA	-	4	6	Ω
		V _{GS} =4.5V, I _D =200mA	-	4.2	9	
Zero Gate Voltage Drain Current	IDSS	V _{DS} =80V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	lgss	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	-	<u>+</u> 10	uA
Dynamic ^(Note 5)						
Total Gate Charge	Qg	V _{DS} =30V, I _D =200mA, V _{GS} =10V ^(Note 1,2)	-	1.8	-	nC
Gate-Source Charge	Q_{gs}		-	0.4	-	
Gate-Drain Charge	Q _{gd}		-	0.3	-	
Input Capacitance	Ciss	V _{DS} =25V, V _{GS} =0V, f=1MHZ	-	45	-	pF
Output Capacitance	Coss		-	14	-	
Reverse Transfer Capacitance	Crss		-	7.8	-	
Turn-On Delay Time	td _(on)	$V_{DD}=30V, I_{D}=200mA, V_{GS}=10V, R_{G}=6\Omega^{(Note 1,2)}$	-	3.4	-	
Turn-On Rise Time	tr		-	19	-	
Turn-Off Delay Time	td _(off)		-	8.2	-	ns
Turn-Off Fall Time	tf	NG=012(*******)=/	-	20	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	la la	ls			400	mA
Diode Forward Current	IS		-	-	400	IIIA
Diode Forward Voltage	V _{SD}	Is=400mA, V _{GS} =0V	-	0.9	1.3	V

NOTES :

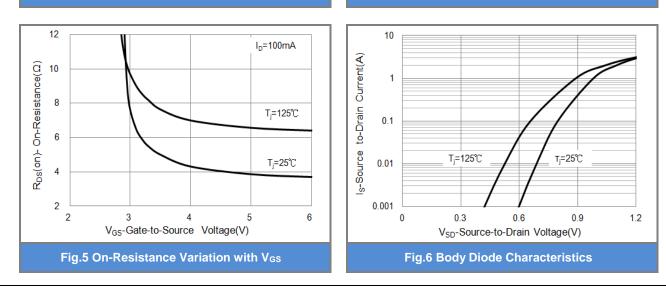
1. Pulse width

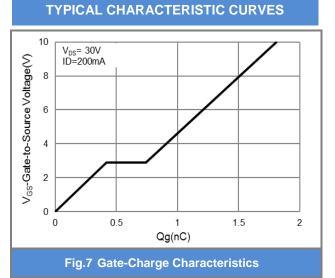
2. Essentially independent of operating temperature typical characteristics.

3. Reja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.

- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.

SEM CONDUCTOR **PJA3476-AU TYPICAL CHARACTERISTIC CURVES** 500 500 V_{DS}=5V V_{GS}=10V, 8V, 6V, 4.5V I_{DS}-Drain-to-S ource Current(mA) I_{DS}-Drain-to-Source Current(mA) 400 400 V_{GS}=3.5V 300 300 200 200 V_{GS}=3V T_**=25℃** T_=125℃ 100 100 0 0 0 2 4 6 8 10 5 1 2 3 4 V_{DS}- Drain-to-Source Voltage(V) V_{GS}-Gate-to-Source Voltage(V) **Fig.1 On-Region Characteristics Fig.2 Transfer Characteristics** 10 2.4 R_{DS}(on)- On-Resistance (Normalized) $R_{DS}(on)$ - On-Resistance(Ω) 8 2.0 V_{GS}=10V, I_D=300mA 1.6 6 V_{GS}=4.5V, I_D=200mA V_{GS}= 4.5V 1.2 4 V_{GS}= 10V 0.8 2 0 50 25 75 100 125 150 175 0 150 300 450 600 I_{DS}-Drain-to-Source Current(mA) Temperature (℃) Fig.4 On-Resistance vs. Junction temperature Fig.3 On-Resistance vs. Drain Current





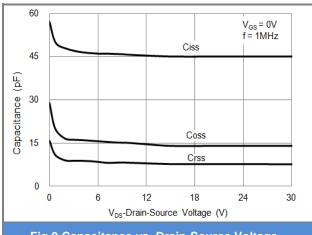
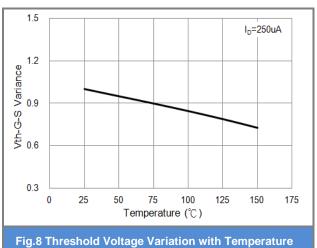


Fig.9 Capacitance vs. Drain-Source Voltage



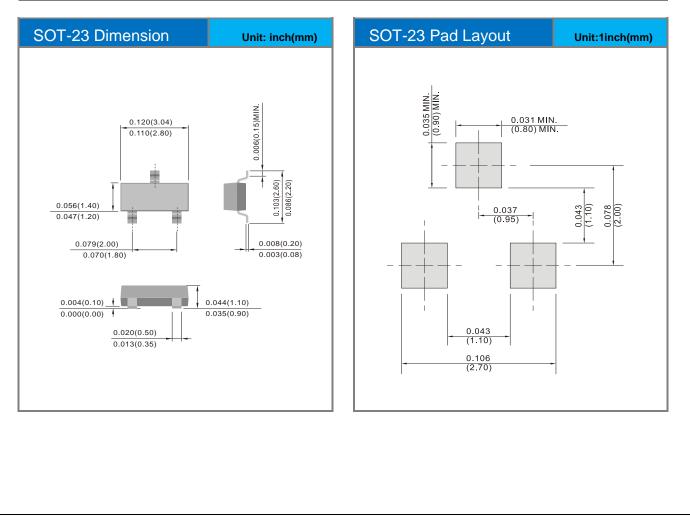




Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJA3476-AU_R1_000A1	SOT-23	3K pcs / 7" reel	A76	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout





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